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Features

- Stealth Recovery t_{rr} = 300 ns (@ I_F = 18 A)
- Max Forward Voltage, V_F = 3.3 V (@ T_C = 25°C)

18 A, 1200 V, STEALTH™ Diode

ISL9R18120G2, ISL9R18120P2,

- 1200 V Reverse Voltage and High Reliability
- Avalanche Energy Rated

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ISL9R18120S3S

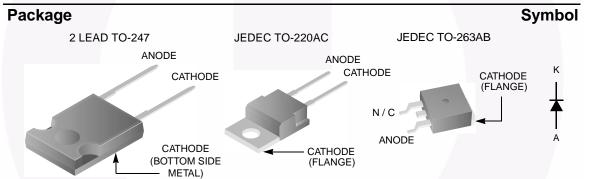
RoHS Compliant

Applications

- Hard Switched PFC Boost Diode
- UPS Free Wheeling Diode
- Motor Drive FWD
- SMPS FWD
- Snubber Diode

Description

The ISL9R18120G2, ISL9R18120P2, ISL9R18120S3S is a STEALTH[™] diode optimized for low loss performance in high frequency hard switched applications. The STEALTH[™] family exhibits low reverse recovery current (I_{RR}) and exceptionally soft recovery under typical operating conditions. This device is intended for use as a free wheeling or boost diode in power supplies and other power switching applications. The low I_{RR} and short ta phase reduce loss in switching transistors. The soft recovery minimizes ringing, expanding the range of conditions under which the diode may be operated without the use of additional snubber circuitry. Consider using the STEALTH[™] diode with an SMPS IGBT to provide the most efficient and highest power density design at lower cost.



Device Maximum Ratings T_c = 25°C unless otherwise noted

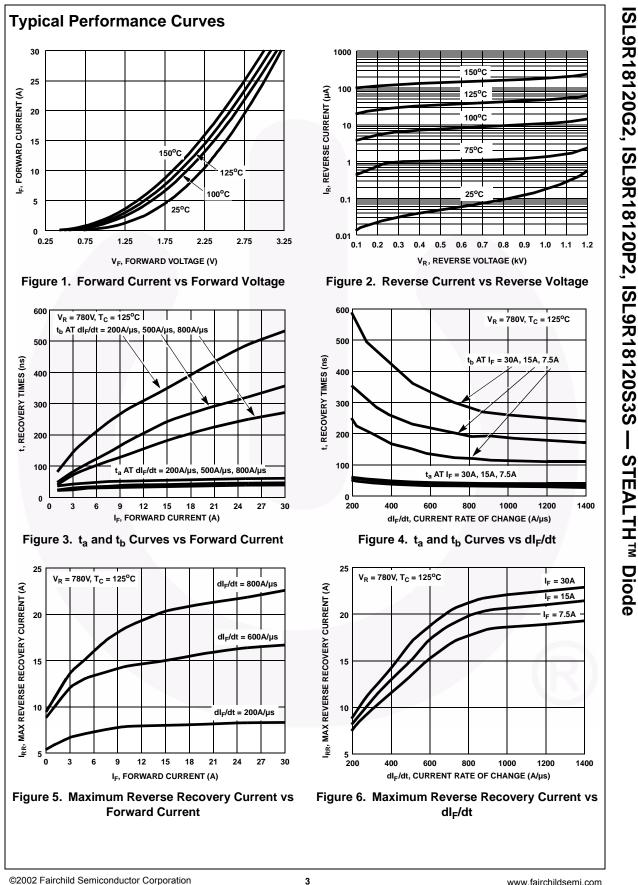
Symbol	Parameter	Rating	Unit
V _{RRM}	Repetitive Peak Reverse Voltage	1200	V
V _{RWM}	Working Peak Reverse Voltage	1200	V
V _R	DC Blocking Voltage	1200	V
I _{F(AV)}	Average Rectified Forward Current (T _C = 92°C)	18	A
I _{FRM}	Repetitive Peak Surge Current (20kHz Square Wave)	36	A
I _{FSM}	Nonrepetitive Peak Surge Current (Halfwave 1 Phase 60Hz)	200	А
PD	Power Dissipation	125	W
E _{AVL}	Avalanche Energy (1A, 40mH)	20	m
T _J , T _{STG}	Operating and Storage Temperature Range	-55 to 175	°C
ΤL	Maximum Temperature for Soldering	300	°C
T _{PKG}	Leads at 0.063in (1.6mm) from Case for 10s Package Body for 10s, See Application Note AN-7528	260	°C

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Part Number Top Mark		Package	e Packing N	lathod	Таре	Width		Quar	ntity	
ISL9R18120G2 R18120G2		TO-247	Tube	;	N	/A		30)	
ISL9R18120P2 R18120P2 T		TO-220A	C Tub	е	N	/A		50)	
ISL9R18120S3S R18120S3 TO-263A		B Reel 24r		mm		800				
lectric	al Cha	racteristics	S T _C = 25°C	unless otherwise	e note	d				
Symbol		Parameter		Test	Condit	ions	Min	Тур	Max	Unit
ff State	Charac	teristics							•	
I _R	Instantan	eous Reverse Cu	rrent	V _R = 1200 V	Т	_C = 25°C	-	-	100	μA
i v						_C = 125°C	-	-	1.0	mA
n State	Charac	teristics						•	•	
V _F		eous Forward Vol	tage	I _F = 18 A	Т	_C = 25°C	-	2.7	3.3	V
• F	inotantan					_C = 125°C	-	2.5	3.1	V
vnomio	Charao	toriction	_			0				1
		capacitance	_	V _R = 10 V, I _F =	0 A	_	-	69	- 1	pF
			-		• • •		l			μ.
		cteristics						-		
t _{rr}	Reverse	Recovery Time		$I_F = 1 A, dI_F/dt =$			-	38	45	ns
				IF = 18 A, dIF/dt =	= 100 A	/µs, V _R = 30 V	-	60	70	ns
t _{rr}		Recovery Time		$I_{F} = 18 \text{ A,}$ $dI_{F}/dt = 200 \text{ A/}\mu\text{s,}$ $V_{R} = 780 \text{ V, } T_{C} = 25^{\circ}\text{C}$		-	300	-	ns	
l _{rr}		Recovery Current				-	6.5	-	A	
Q _{rr}		Recovered Charg	e				-	950	-	nC
t _{rr}		Recovery Time	_	$I_F = 18 \text{ A},$ $dI_F/dt = 200 \text{ A/}\mu\text{s},$ $V_R = 780 \text{ V},$ $T_C = 125^{\circ}\text{C}$			-	400	-	ns
S		Factor (t _b /t _a)	_				-	7.0	-	-
I _{rr}		Recovery Current					-	8.0	-	A
Q _{rr}		e Recovered Charge e Recovery Time					-	2.0	-	μC
t _{rr} S				I _F = 18 A, dI _F /dt = 1000 A/μs,			-	235	-	ns
		Factor (t _b /t _a)			$V_{\rm R} = 780 \text{ V},$			5.2 22	-	-
I _{rr}		Recovery Current		T _C = 125°C			-	2.1	-	A µC
Q _{rr} dl _M /dt		erse Recovered Charge kimum di/dt during t _b		+				370	-	μc A/μs
	1						-	570		πμο
	1	teristics		I			1	T		
R _{θJC}		Resistance Juncti		TO-247, TO-220, TO-263		-	-	1.0	°C/W	
R _{θJA}		Resistance Juncti					-	-	30	°C/W
νθJΑ	mermal			10-220, 10-20	0		-		02	°C/W
R _{θJA}	Thermal	Resistance Juncti	on to Ambien	t TO-220, TO-26	3		-	-	62	°C

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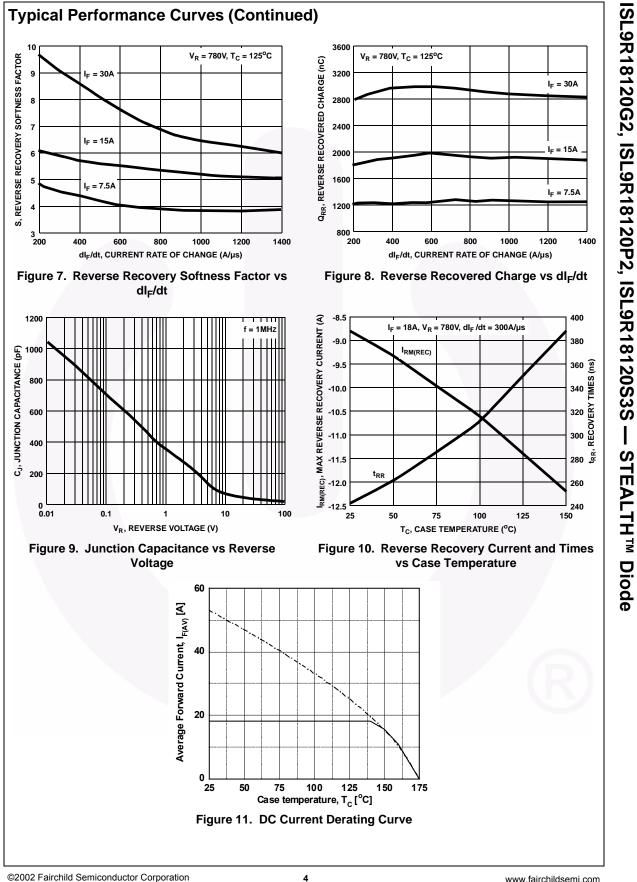
ISL9R18120G2, ISL9R18120P2, ISL9R18120S3S — STEALTH™ Diode



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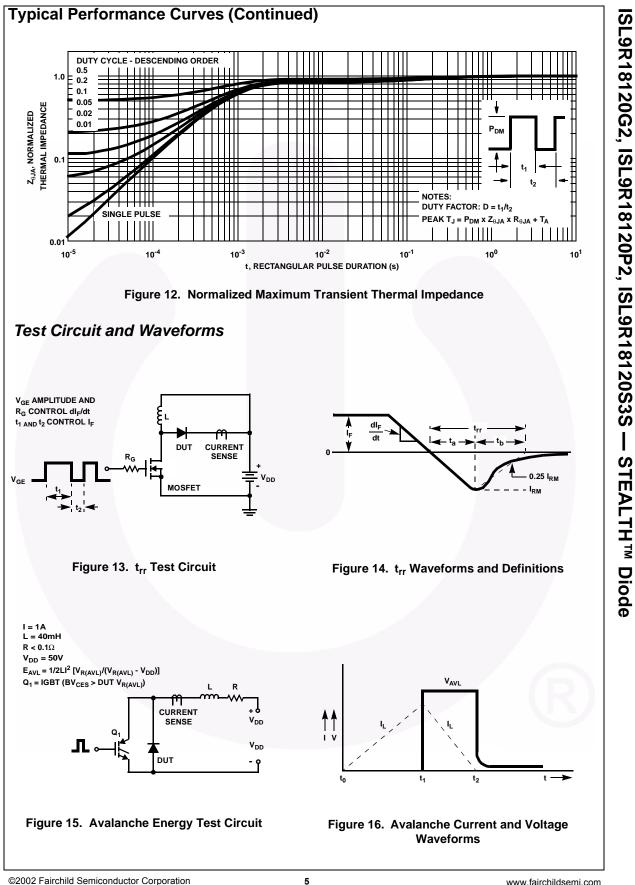
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ISL9R18120G2, ISL9R18120P2,



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Mechanical Dimensions

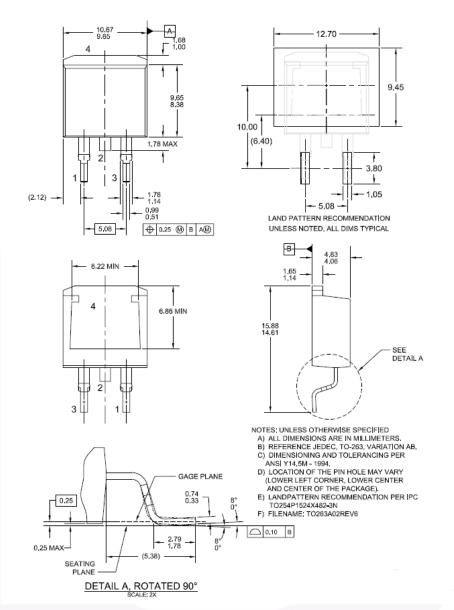


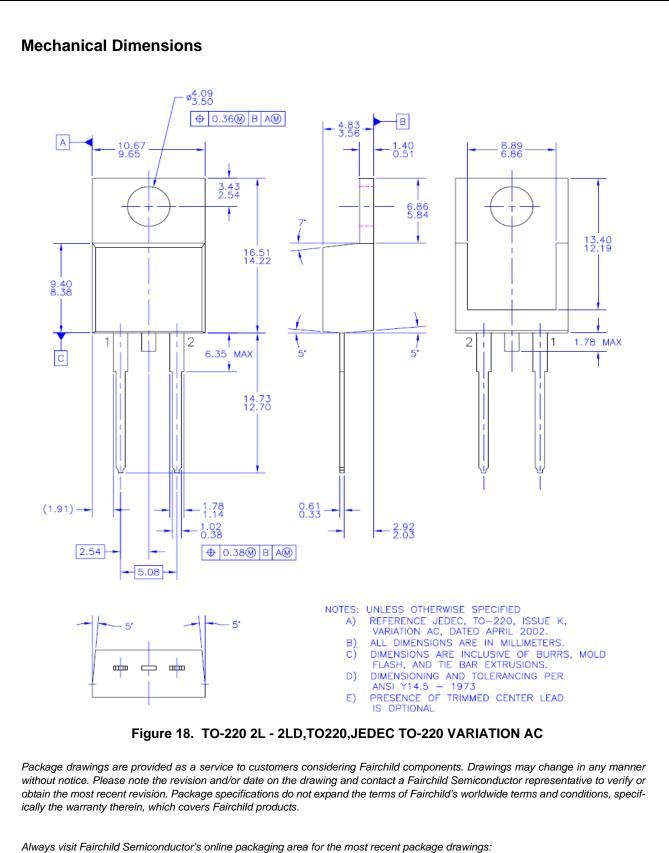
Figure 17. TO-263 2L (D²-PAK) - 2LD,TO263, SURFACE MOUNT

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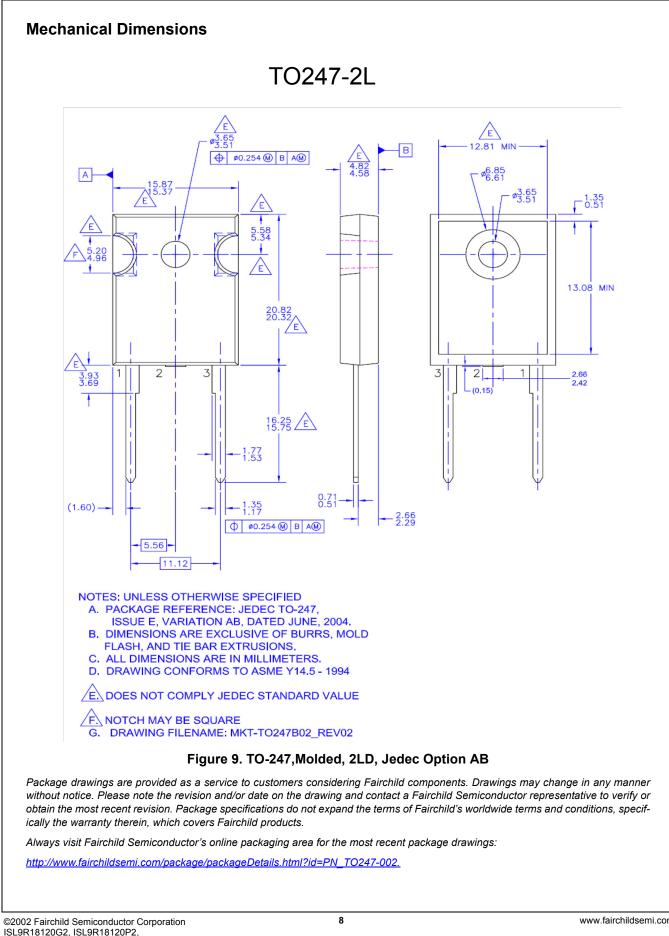


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— STEALTH[™] Diode



ISL9R18120S3S Rev. C2

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